

SPL TR85

Metal Can® TO56

Infrared Laser Diode in TO56 Package



Applications

- Gesture Recognition

Features:

- Laser wavelength 850 nm
- Efficient radiation source for cw and pulsed operation
- Single tranverse mode semiconductor laser
- High modulation bandwidth
- TO56 package with photo diode

Ordering Information

Type	Peak output power typ. $T_{case} = 25\text{ }^{\circ}\text{C}$ P_{opt}	Ordering Code
SPL TR85	200 mW	Q65112A1150

Maximum Ratings

Parameter	Symbol		Values
Operating temperature	T_{op}	min.	-20 °C
		max.	60 °C
Storage temperature	T_{stg}	min.	-40 °C
		max.	85 °C
Peak output power	P_{opt}	max.	220 mW
Forward current	I_F	max.	260 mA
Reverse voltage ¹⁾	V_R	max.	3 V
Reverse voltage of photodiode	V_{RPF}	max.	30 V
Soldering temperature $t_{max} = 10\text{ s}$	T_S		260 °C

Operation outside these conditions may damage the device. Operation at maximum ratings may influence lifetime.

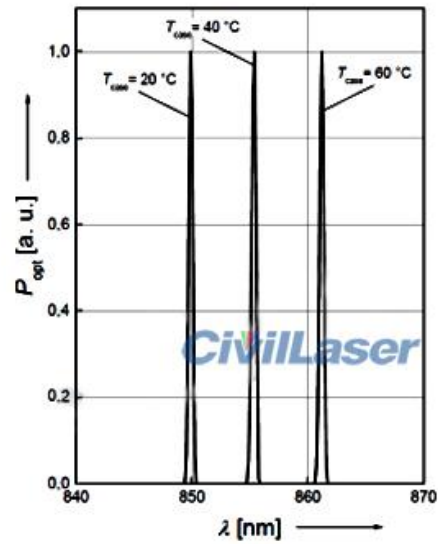
Characteristics

$P_{\text{opt}} = 200 \text{ mW}$; $T_{\text{case}} = 25 \text{ °C}$

Parameter	Symbol		Values
Forward current	I_F	typ. max.	225 mA 255 mA
Peak wavelength	λ_{peak}	min. typ. max.	840 nm 850 nm 860 nm
Spectral bandwidth at 50% $I_{\text{e,rel,max}}$	$\Delta\lambda$	typ.	3 nm
Beam divergence (FWHM) parallel to pn-junction	$\Theta_{\parallel}$	typ.	6 °
Beam divergence (FWHM) perpendicular to pn-junction	$\Theta_{\perp}$	typ.	19 °
Monitor current ²⁾³⁾	I_m	min. typ.	300 μA 500 μA
Threshold current	I_{th}	typ. max.	56 mA 85 mA
Forward voltage	V_F	typ. max.	1.77 V 2.20 V
TE polarization	P_{TE}	typ.	20:1
Modulation frequency	f	min.	100 MHz
Thermal resistance junction case real	R_{thJC}	typ.	50 K / W

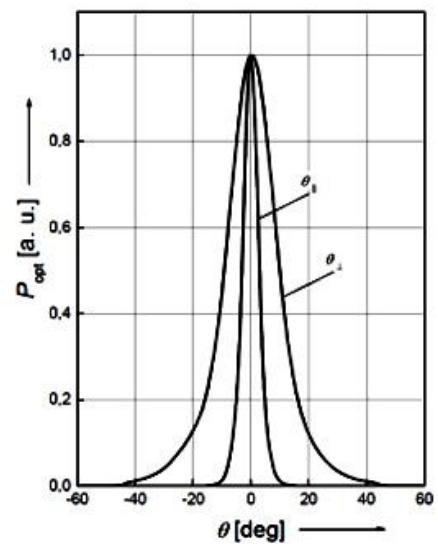
Relative Spectral Emission ⁴⁾

$$P_{\text{opt}} = f(\lambda)$$



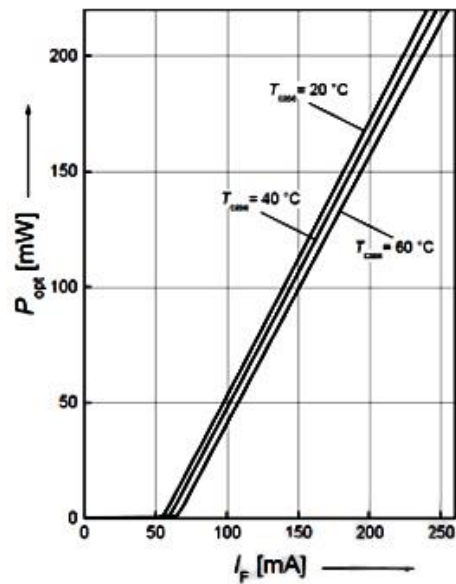
Beam Divergence ⁴⁾

$$P_{\text{opt}} = f(\theta), T_{\text{case}} = 25^\circ\text{C}$$

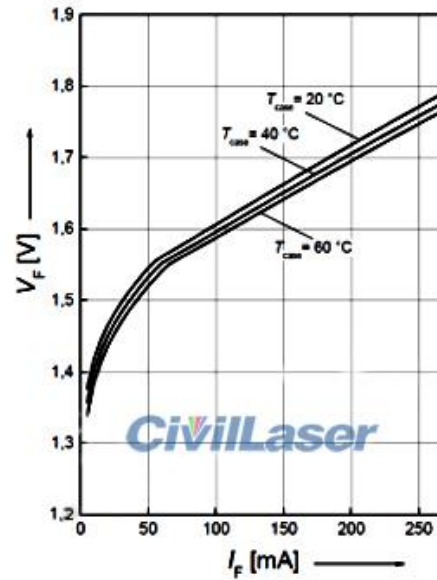


Optical Output Power ⁴⁾

$$P_{\text{opt}} = f(I_F)$$

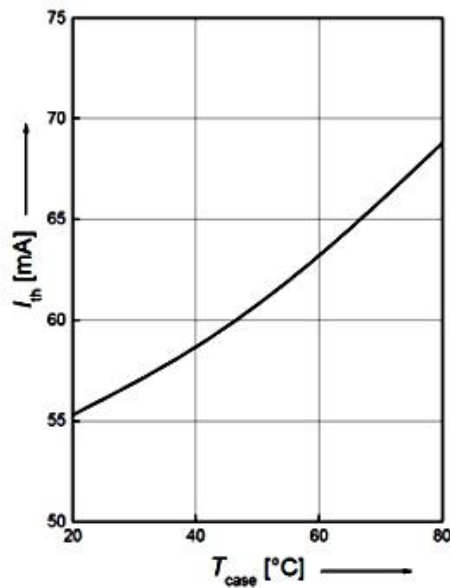
Operating Voltage ⁴⁾

$$V_F = f(I_F)$$

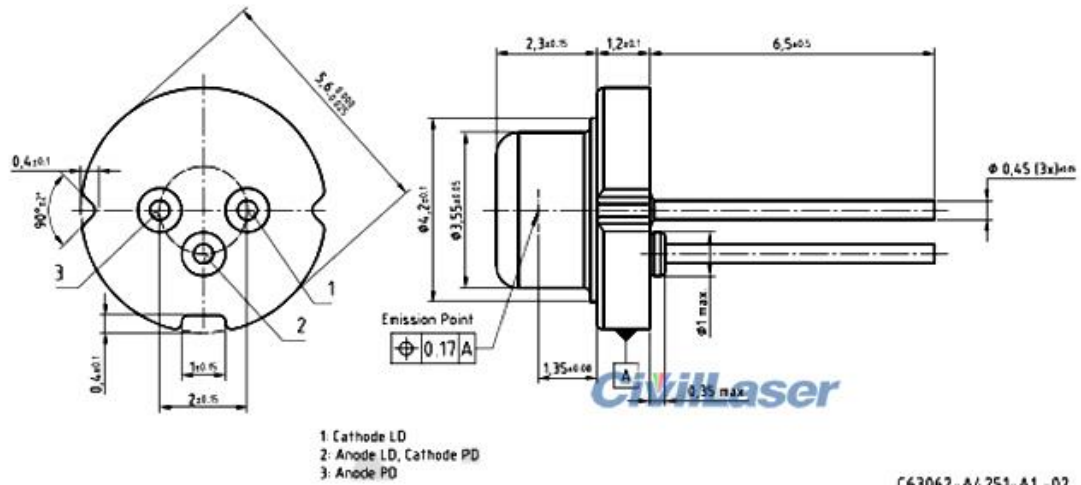


Threshold Current

$$I_{\text{th}} = f(T_{\text{case}})$$

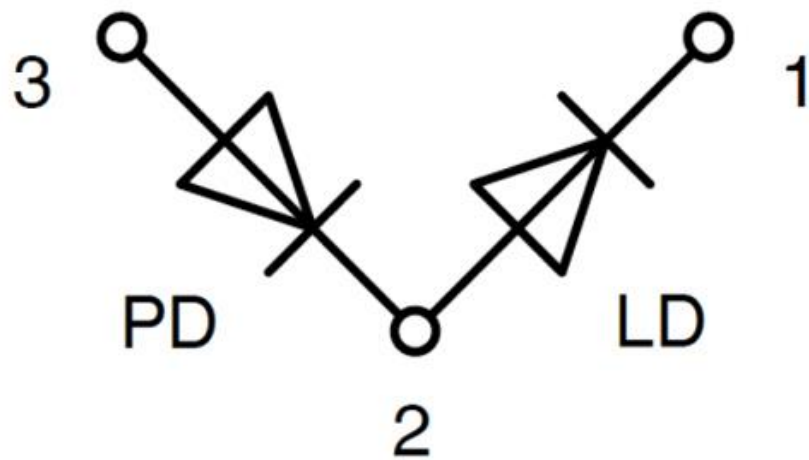


Dimensional Drawing ⁵⁾



Approximate Weight: 310.0 mg

Electrical internal circuit



Pin	Description
1	LD Cathode
2	LD Anode, PD Cathode (case)
3	PD Anode